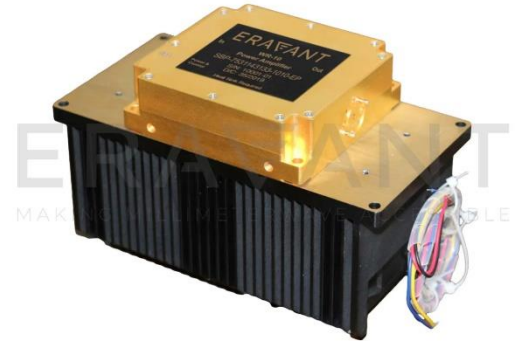


## SBP-7137633633-1212-EP

### E-Band Power Amplifier, 71 to 76 GHz, 36 dB Gain, +33 dBm P<sub>sat</sub>

**SBP-7137633633-1212-EP** is a E-Band, GaAs power amplifier with a typical small signal gain of 36 dB and a nominal P<sub>sat</sub> of +33 dBm across the frequency range of 71 to 76 GHz. The DC power requirement for the amplifier is +6 V<sub>DC</sub>/6 A. The mechanical configurations is an inline structure with WR-12 waveguides and UG-387/U anti-cocking flanges. Power amplifier module comes with heatsink and fan assembled with the unit.



#### Electrical Specifications:

| Parameter                          | Minimum            | Typical                    | Maximum |
|------------------------------------|--------------------|----------------------------|---------|
| Frequency                          | 71 GHz             |                            | 76 GHz  |
| Small Signal Gain                  |                    | 36 dB                      |         |
| P <sub>1dB</sub>                   |                    | +31 dBm                    |         |
| P <sub>sat</sub>                   |                    | +33 dBm                    |         |
| P <sub>in</sub> @ P <sub>sat</sub> |                    | 0 dBm                      | +5 dBm  |
| Input Return Loss                  |                    | 8 dB                       |         |
| Output Return Loss without Damage  |                    | 5 dB                       |         |
| DC Supply Voltage (VDD)            | +5 V <sub>DC</sub> | +6 V <sub>DC</sub>         |         |
| DC Supply Current                  |                    | 6.0 A                      |         |
| Supply Voltage to Fan              |                    | +12 V <sub>DC</sub> /0.7 A |         |
| Specification Temperature          |                    | +25 °C                     |         |
| Operating Temperature              | 0 °C               |                            | +50 °C  |

#### Mechanical Specifications:

| Item          | Specification                                    |
|---------------|--|
| Input         | WR-12 Waveguide with UG-387/U Anti-Coking Flange |
| Output        | WR-12 Waveguide with UG-387/U Anti-Coking Flange |
| Power Supply  | Solder Pin                                       |
| Case Material | Aluminum   |
| Finish        | Gold Plated                                      |
| Size          | 3.35" (L) X 4.33" (W) X 3.46" (H)                |
| Outline       | BP-HE-A-H2                                       |

#### ECCN

3A001.b.4

#### FEATURES

- Class AB GaAs Technique
- Broadband Performance
- High Gain
- High Output Power
- Forced Air Cooling
- In-line Port Configuration

#### APPLICATIONS

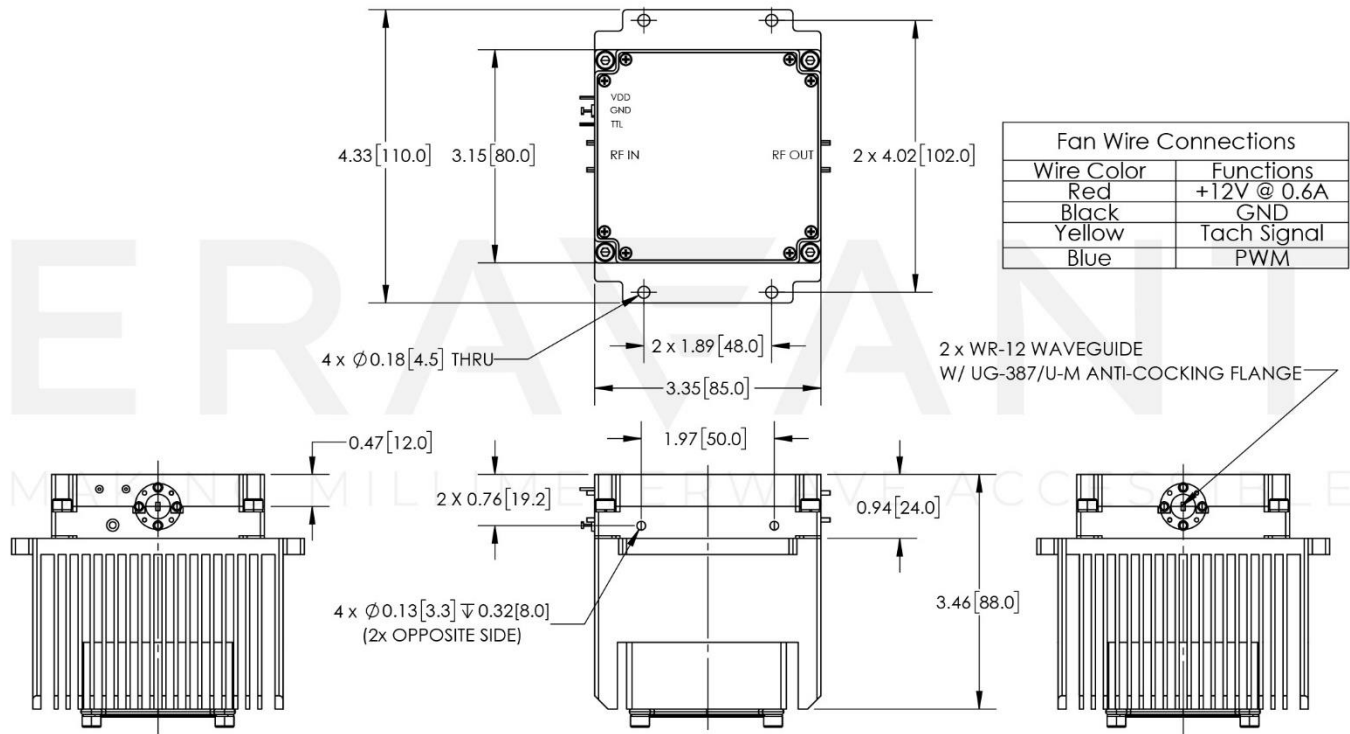
- Radar Systems
- Communication Systems
- Test Equipment

#### SUPPLEMENTAL DETAILS



## SBP-7137633633-1212-EP

**Mechanical Outline:** (Unless otherwise specified, all dimensions are in inches [millimeters])



### NOTE:

- The product picture does not represent the final product
- All data presented is collected from a sample lot. Actual data may vary unit to unit.
- All testing was performed under +25 °C case temperature.
- Other mechanical configurations are available under different model numbers.
- Eravant reserves the right to change the information presented without notice.

### CAUTION:

- Exceeding absolute maximum ratings shown will damage the device.
- Do not block the air inlets and outlets.
- The device is static sensitive. Always follow ESD rules when working with the device.
- Do not plug or unplug any connectors when amplifier is activated. All connectors must be connected/disconnected when amplifier is off.
- The case temperature of the device shall never exceed +50 °C. Use proper heatsink or fan if necessary
- Any foreign objects in the waveguide will degrade performance and/or damage the device.